Vishay Semiconductors

High Performance Schottky Rectifier, 1.0 A



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SMB (DO-214AA)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	1.0 A				
V _R	15 V				
V _F at I _F	0.21 V				
I _{RM}	35 mA at 100 °C				
T _J max.	125 °C				
E _{AS}	1.0 mJ				
Package	SMB (DO-214AA)				
Circuit configuration	Single				

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- 125 °C T_J operation ($V_R < 5 V$)
- · Optimized for OR-ing applications
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

The VS-10BQ015HM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	1.0	А			
V _{RRM}		15	V			
I _{FSM}	t _p = 5 μs sine	140	А			
V _F	1.0 A _{pk} , T _J = 125 °C	0.21	V			
TJ	Range	-55 to +125	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-10BQ015HM3	UNITS			
Maximum DC reverse voltage	V _R	15	V			
Maximum working peak reverse voltage	V _{RWM}	25	V			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS		UNITS	
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_L = 134 °C	, rectangular waveform	1.0	А	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load	140		
non-repetitive surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	40	A	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 2 mH		1.0	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		1.0	А	

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
	V _{FM} ⁽¹⁾	1 A	T _{.1} = 25 °C	0.33	V	
Maximum forward voltage drop See fig. 1		2 A	1j=25 C	0.39		
		1 A	T _{.1} = 125 °C	0.21		
		2 A	1j = 125 C	0.29		
Maximum reverse leakage current	I _{RM}	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.5	mA	
See fig. 2		T _J = 100 °C	V _R = naleu V _R	35		
Threshold voltage	V _{F(TO)}		-	V		
Forward slope resistance	r _t	$T_J = T_J maximum$	-	mΩ		
Typical junction capacitance	CT	$V_R = 5 V_{DC}$, (test signal ran	390	pF		
Typical series inductance	Ls	Measured lead to lead 5 n	2.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R 10 0			V/µs	

Note

 $^{(1)}\,$ Pulse width = 300 $\mu s,$ duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	T _J ⁽¹⁾		-55 to +125	°C		
Maximum storage temperature range	T _{Stg}		-55 to +150	C		
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation See fig. 4	36	°C/W		
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	0/14		
Approximate weight			0.10	g		
Approximate weight			0.003	oz.		
Marking device		Case style SMB (DO-214AA)	1	С		

Notes

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink (1)

(2) Mounted 1" square PCB



VS-10BQ015HM3

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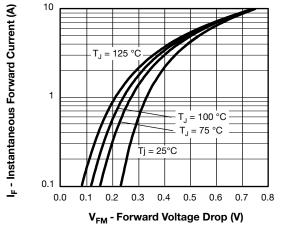


Fig. 1 - Maximum Forward Voltage Drop Characteristics

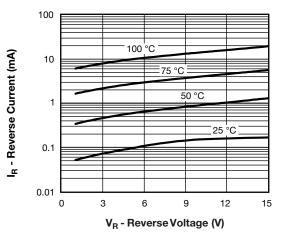


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

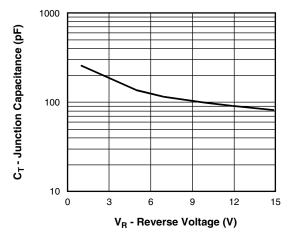


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

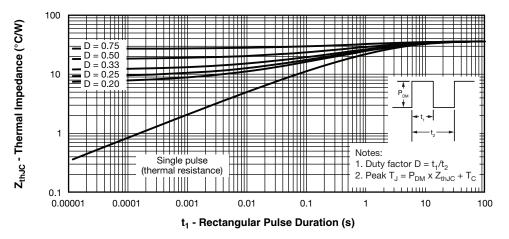
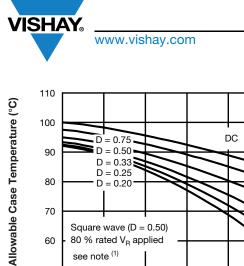


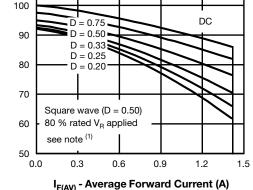
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

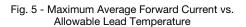
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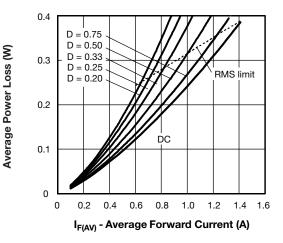


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

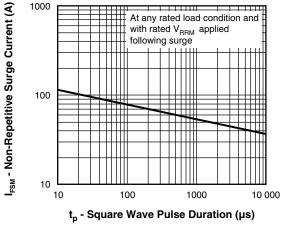


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

- (1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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ORDERING INFORMATION TABLE

Device code	VS-	10	В	Q	015	Н	M3
		2	3	4	5	6	7
	1	- Visl	nay Sen	niconduc	ctors pro	oduct	
	2	- Cur	rent rati	ng			
	3	- В=	SMB				
	4	- Q =	Schott	ky "Q" se	eries		
	5	- Vol	tage rati	ng (015	= 15 V))	
	6	- Н=	AEC-Q	101 qua	lified		
	7	- Env	vironmer	ntal digit	:		
		М3	= halog	en-free,	RoHS of	compliar	nt and t

ORDERING INFORMATION (Example)						
PREFERRED P/N	PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-10BQ015HM3/5BT	5BT	3200	13" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95401			
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			
SPICE model	www.vishay.com/doc?95666			

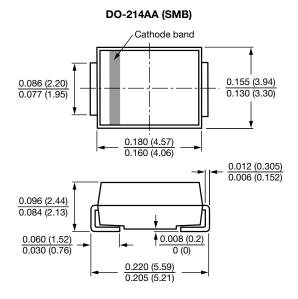


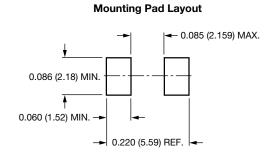
Outline Dimensions

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SMB

DIMENSIONS in inches (millimeters)







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